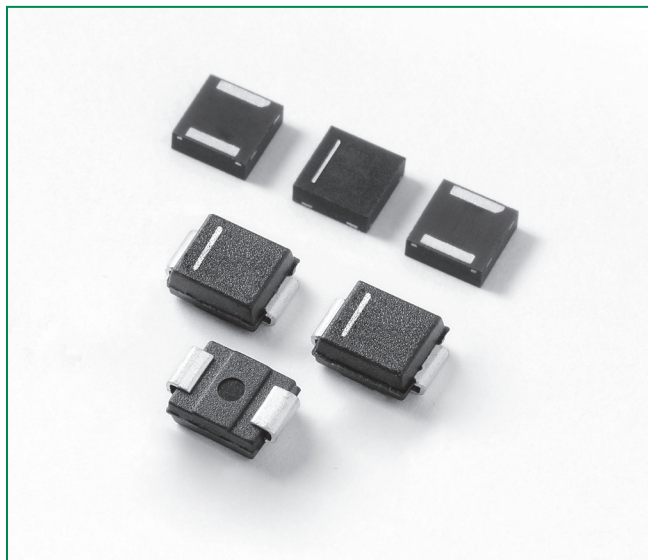


PLED Unidirectional Series (PLEDxUx)



Description

PLED Unidirectional Series (PLEDxUx Series) open LED protectors provide a switching electronic shunt path around a single LED that fails as an open circuit. This ensures the remaining string of LEDs will continue to function even though a single LED in the string has failed open. It also provides reverse battery or reverse power polarity protection.

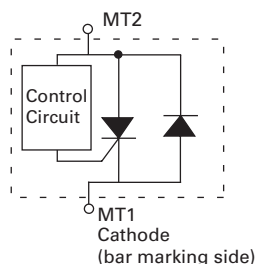
PLED Unidirectional Series devices were designed to enable higher reliability in outdoor LED lighting applications such as street lighting, outdoor signage, aircraft runway lighting, roadside warning lights and other applications.

Compatible with one, two and three watt LEDs that have a nominal 3V forward characteristic, PLED Unidirectional Series devices are available in two surface mount packages, the DO-214AA and the Quad Flat Pak No-lead (QFN). The QFN's low profile, chip scale package (CSP) is ideal for dense board applications.

Agency Approvals

Agency	Agency File Number
	E133083

Schematic Symbol



Features & Benefits

- Fast switching
- Reverse Battery/Power Protection
- Automatically resets after power cycle
- Available in low profile, small footprint QFN and Standard DO214AA packages
- Compatible with industrial lighting environments
- Compatible with PWM frequencies up to 10 kHz
- RoHS compliant and halogen-free

Electrical Characteristics (All parameters are measured at T=25°C unless otherwise noted)

Part Number	Marking	V _{BR} breakdown		V _{DRM} breakdown	I _H	I _S	I _T @V _T	V _T @ I _T = 1 Amp	I _F @V _F	V _F @ I _F = 1 Amp	Critical rate of rise dV/dt
		Volts		Volts	mAmps	mAmps	Amps	Volts	Amps	Volts	Volts
		Min	Max	Min	Max	Max	Max	Max	Max	Max	Max
PLED6UQ12	PL6U	6	16	6	30	50	1.0	1.2	1.0	1.0	250V/μs
PLED6US	PL6U										
PLED9UQ12	PL9U	9	18	9							
PLED9US	PL9U										
PLED13UQ12	PL13U	13	26	13							
PLED13US	PL13U										
PLED18UQ12	PL18U	18	33	18							
PLED18US	PL18U										

Thermal Considerations

Package	Symbol	Parameter	Value	Unit
 	T_J	Operating Junction Temperature Range	-40 to +150	°C
	T_S	Storage Temperature Range	-65 to +150	°C
	$R_{\theta JA}$	Thermal Resistance: Junction to Ambient	DO-214AA: 90 ¹ DO-214AA: 40 ² QFN: 120 ¹ QFN: 60 ³	°C/W

Notes:

1) Standard FR-4 PCB with Copper Pads (Recommended Size)

2) Aluminum PCB

Thickness: 1.6mm

Grade: 1-2 W/mK Thermal Conductivity

Trace thickness: 2 oz

Insulation layer thickness: 215 µm

Solder Pad Dimensions: 2.0mm x 2.8mm (Recommended Size)

3) Aluminum PCB

Thickness: 1.6mm

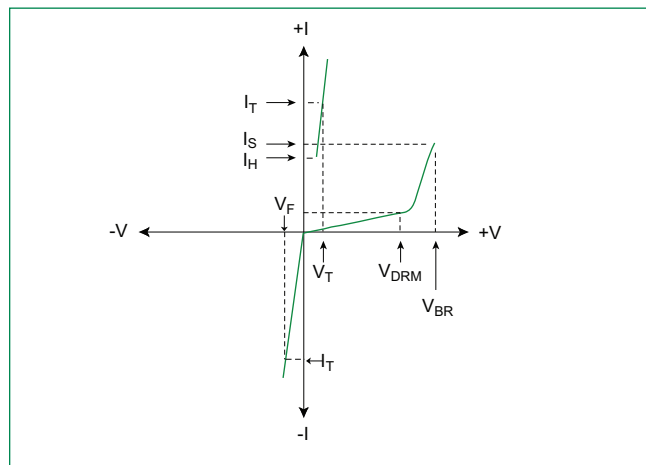
Grade: 1-2 W/mK Thermal Conductivity

Trace thickness: 2 oz

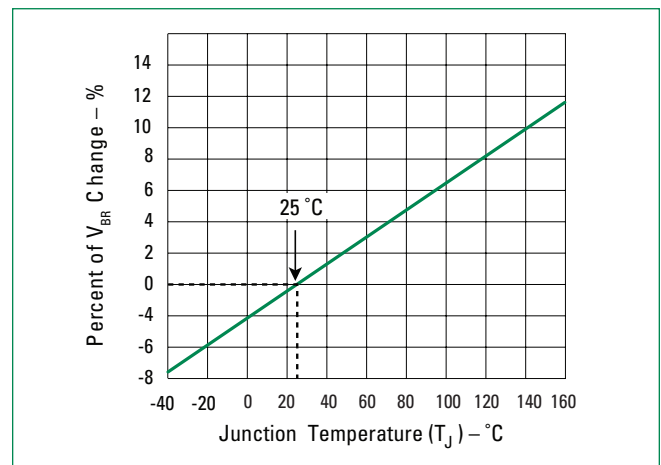
Insulation layer thickness: 60 µm

Solder Pad Dimensions: 1.27mm x 2.54mm (Recommended Size)

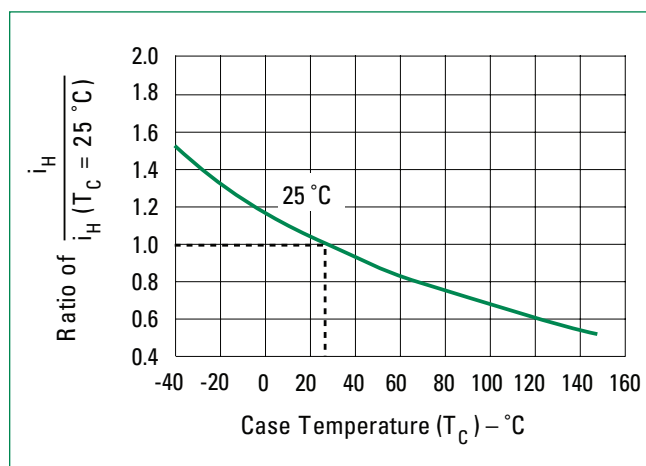
V-I Characteristics



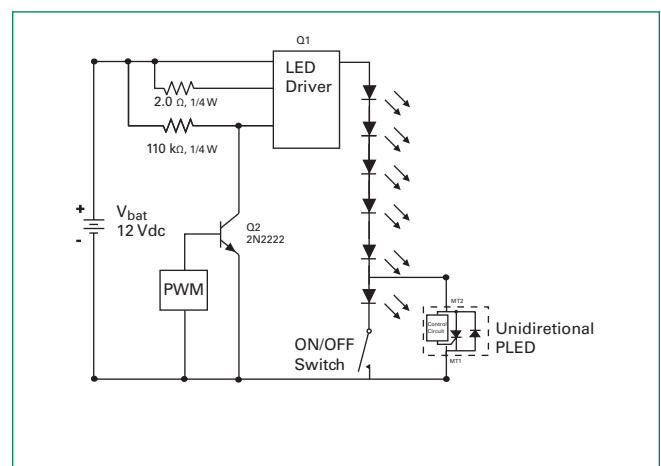
V_{BR} vs. Junction Temperature



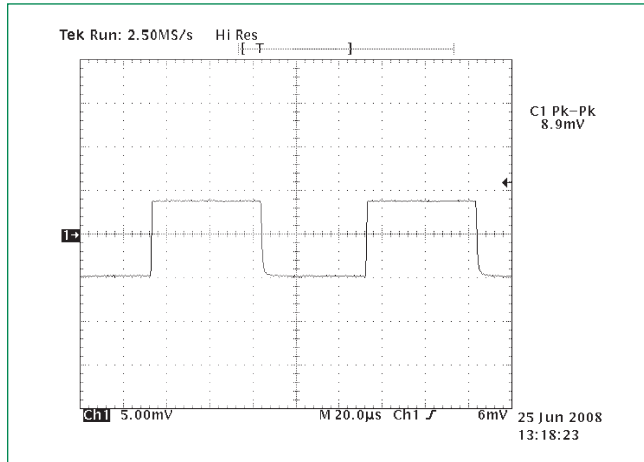
Normalized DC Holding Current vs. Case Temperature



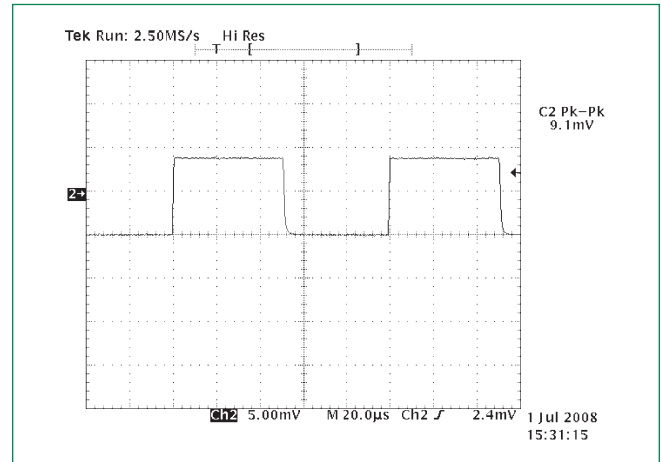
LED Interference Test Circuit



6 LEDs in Series 50% Duty Cycle 10kHz

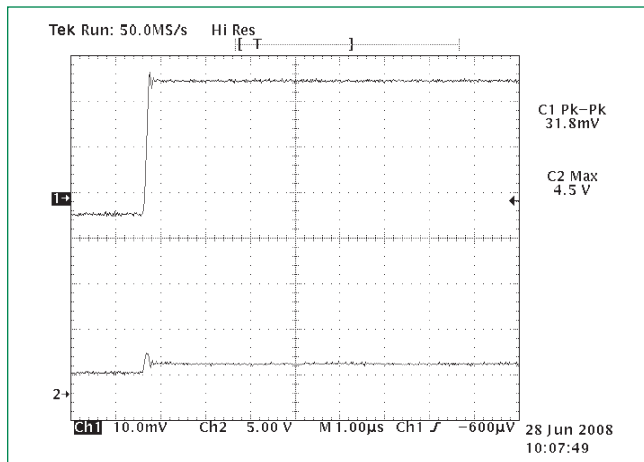


5 LEDs and 1 PLED in Series 50% Duty Cycle 10kHz



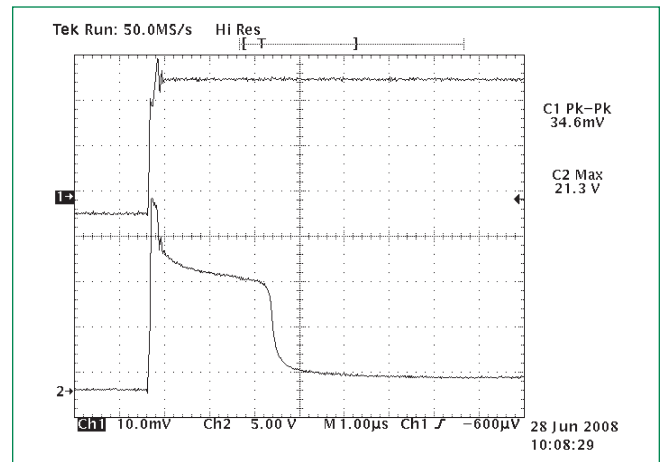
Note: These two graphs show the current magnitude through the LED string with and without the PLED included. There is no noticeable effect on the LED current magnitude when the PLED is included in the circuit as compared to the LED current magnitude when the PLED is not in the circuit. (The conversion factor for the test measurement in the graphs above is 10mA/mV for the Pearson coil measurement, therefore, the current magnitude in the first figure is 10mA*8.9 = 89mA, while the second figure is 91mA.)

PLED in the Off-State 10kHz



Channel 1: current through LEDs (318 mA)
Channel 2: voltage across PLED device (4.5 V)

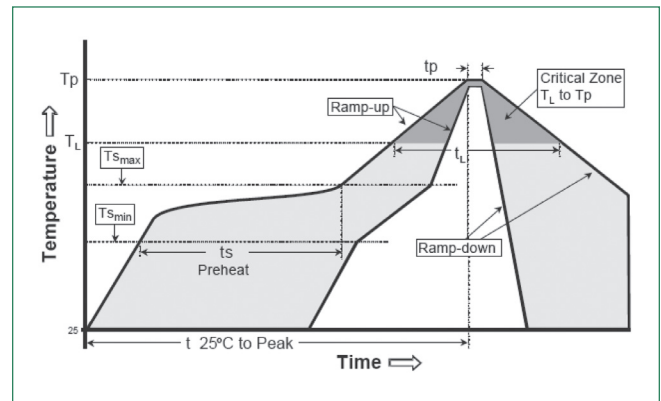
PLED device zeners and then turns fully on 10kHz



Channel 1: current through LEDs (346 mA) and PLED device once it is fully turned on 2.5 µsec later
Channel 2: voltage across PLED device (21.3 V before PLED crowbars with 2 V drop)

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_L) to peak)		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		30 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes max
Do not exceed		260°C



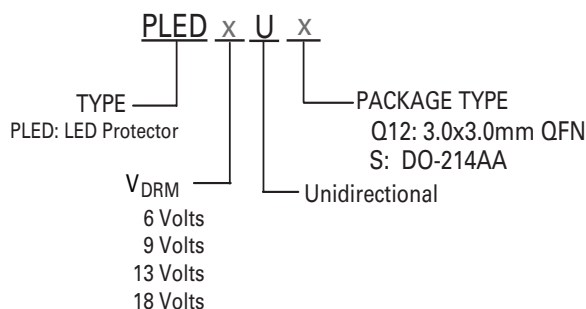
Physical Specifications

Terminal Material	Copper Alloy
Terminal Finish	100% Matte Tin Plated
Body Material	UL recognized epoxy meeting flammability classification 94V-0

Environmental Specifications

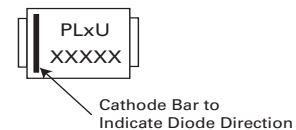
High Temperature Voltage Blocking	MIL-STD-750: Method 1040, Condition A 80% min V_{DRM} (VAC-peak), 150°C, 504 hours
Temperature Cycling	MIL-STD-750: Method 1051 -65°C to 150°C, 15-minute dwell, 100 cycles
Biased Temperature & Humidity	EIA/JEDEC: JESD22-A101 52VDC, 85°C, 85% RH, 1008 hours
High Temperature Storage	MIL-STD-750: Method 1031 150°C, 1008 hours
Low Temperature Storage	-65°C, 1008 hours
Thermal Shock	MIL-STD-750: Method 1056 0°C to 100°C, 5-minute dwell, 10-second transfer, 10 cycles
Resistance to Solder Heat	MIL-STD-750: Method 2031 260°C, 10 seconds

Part Numbering System

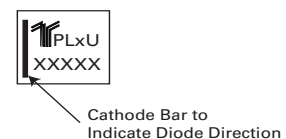


Part Marking System

DO-214AA



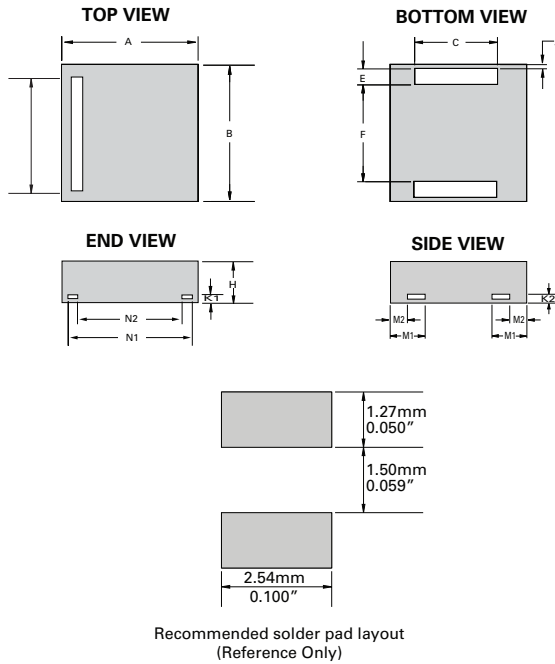
QFN



Packaging

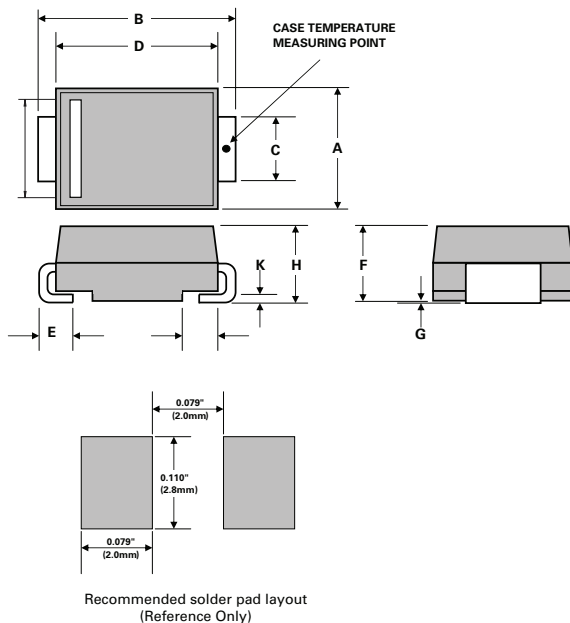
Package	Description	Packaging Quantity	Industry Standard
Q12	QFN 3x3	5000	EIA-481-1
S	DO-214AA	2500	EIA-481-1

Dimensions - QFN (3x3) Package



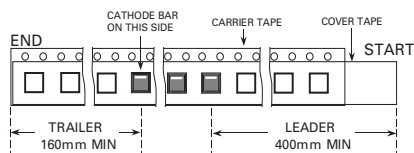
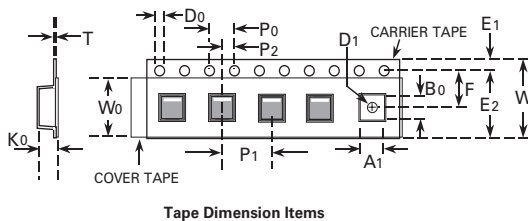
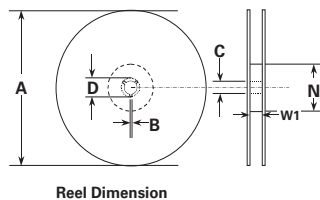
Dimensions	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.114	0.118	0.122	2.900	3.000	3.100
B	0.114	0.118	0.122	2.900	3.000	3.100
C	0.075	0.079	0.083	1.900	2.000	2.100
E	0.011	0.015	0.019	0.285	0.385	0.485
F	0.076	0.080	0.084	1.930	2.030	2.130
H	0.035	0.039	0.043	0.900	1.000	1.100
J	0.000	0.004	0.008	0.000	0.100	0.200
K1	0.004	0.008	0.012	0.100	0.200	0.300
K2	0.004	0.008	0.012	0.100	0.200	0.300
M1	0.056	0.060	0.064	1.143	1.530	1.630
M2	0.038	0.042	0.046	0.970	1.070	1.170
N1	0.096	0.100	0.104	2.440	2.540	2.640
N2	0.082	0.086	0.090	2.080	2.180	2.280

Dimensions - DO-214 AA Package



Dimensions	Inches		Millimeters	
	Min	Max	Min	Max
A	0.130	0.156	3.30	3.95
B	0.201	0.220	5.10	5.60
C	0.077	0.087	1.95	2.20
D	0.159	0.181	4.05	4.60
E	0.030	0.063	0.75	1.60
F	0.075	0.096	1.90	2.45
G	0.002	0.008	0.05	0.20
H	0.077	0.104	1.95	2.65
K	0.006	0.016	0.15	0.41

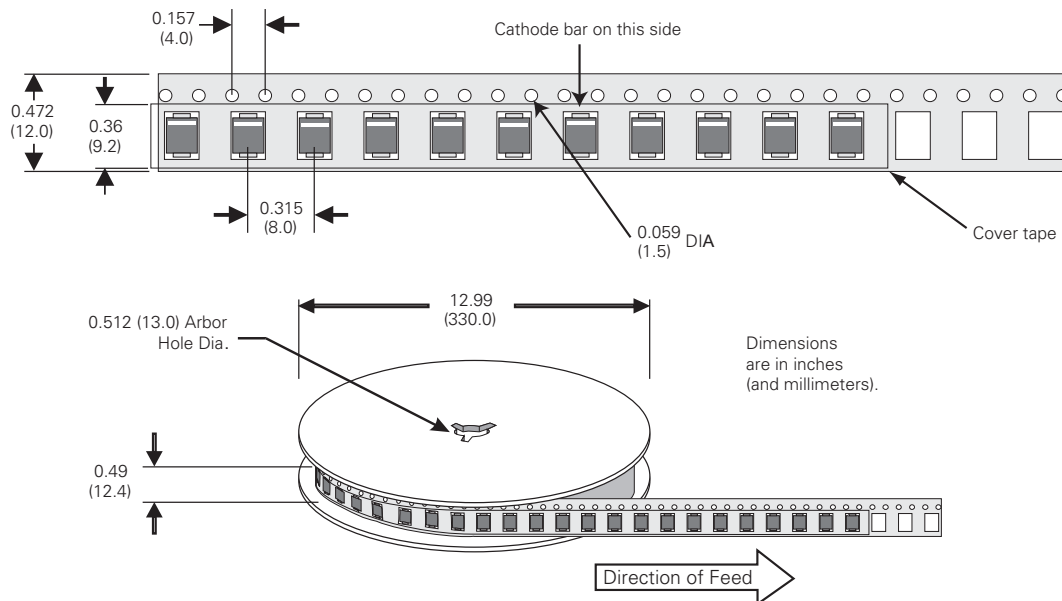
Tape and Reel Specification - QFN (3x3)



Symbols	Description	Inches		Millimeters	
		Minimum	Maximum	Minimum	Maximum
A	Reel Diameter	N/A	12.992	N/A	330.0
B	Drive Spoke Width	0.059	N/A	1.50	N/A
C	Arbor Hole Diameter	0.504	0.531	12.80	13.50
D	Drive Spoke Diameter	0.795	N/A	20.20	N/A
N	Hub Diameter	1.969	N/A	50.00	N/A
W1	Reel Inner Width at Hub	0.488	0.567	12.40	14.40
A0	Pocket Width at bottom	0.126	0.134	3.20	3.40
B0	Pocket Length at bottom	0.126	0.134	3.20	3.40
D0	Feed Hole Diameter	0.059	0.063	1.50	1.60
D1	Pocket Hole Diameter	0.059	N/A	1.50	N/A
E1	Feed hole Position 1	0.065	0.073	1.65	1.85
E2	Feed hole Position 2	0.400	0.408	10.15	10.35
F	Feed hole center-Pocket hole	0.215	0.219	5.45	5.55
K0	Pocket Depth	0.039	0.051	1.00	1.30
P0	Feed hole Pitch	0.153	0.161	3.90	4.10
P1	Component Spacing	0.311	0.319	7.90	8.10
P2	Feed hole center-Pocket hole	0.077	0.081	1.90	2.06
T	Carrier Tape Thickness	0.010	0.014	0.25	0.35
W	Embossed Carrier Tape Width	0.453	0.484	11.50	12.30
W0	Cover Tape Width	0.358	0.366	9.10	9.30

DO-214AA Embossed Carrier Reel Pack (RP)

Meets all EIA-481-1 Standards



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